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April 1st, 2010 Renesas Electronics Corporation

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MOS FIELD EFFECT TRANSISTOR μ PA2744UT1A

SWITCHING N-CHANNEL POWER MOSFET

DESCRIPTION

The μ PA2744UT1A is N-channel MOS Field Effect Transistor designed for DC/DC converter applications.

FEATURES

- Low on-state resistance
- $R_{DS(on)1} = 2.0 \text{ m}\Omega \text{ MAX.} (V_{GS} = 10 \text{ V}, I_{D} = 65 \text{ A})$
- RDS(on)2 = 2.9 m Ω MAX. (VGS = 4.5 V, ID = 33 A)
- Low Q_G
- Thin type surface mount package with heat spreader (8-pin HVSON)
- RoHS Compliant
- Halogen Free

ABSOLUTE MAXIMUM RATINGS (TA = 25°C, All terminals are connected.)

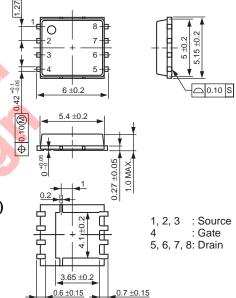
Drain to Source Voltage (VGS = 0 V)	VDSS	30	V
Gate to Source Voltage (VDS = 0 V)	Vgss	±20	V
Drain Current (DC) (Tc = 25°C)	ID(DC)	±65	Α
Drain Current (pulse) Note1	ID(pulse)	±260	Α
Total Power Dissipation Note2	P _{T1}	1.5	W
Total Power Dissipation (PW = 10 sec) Note2	P _{T2}	4.6	W
Total Power Dissipation (Tc = 25°C)	Рт3	83	W
Channel Temperature	Tch	150	°C
Storage Temperature	Tstg	-55 to +150	°C
Single Avalanche Current Note3	las	40	Α
Single Avalanche Energy Note3	Eas	160	mJ

THERMAL RESISTANCE

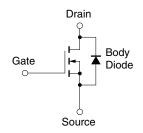
Channel to Ambient Thermal Resistance Note2	Rth(ch-A)	83.3	°C/W
Channel to Case (Drain) Thermal Resistance	Rth(ch-C)	1.5	°C/W

- **Notes 1.** PW \leq 10 μ s, Duty Cycle \leq 1%
 - 2. Mounted on a glass epoxy board of 25.4 mm x 25.4 mm x 0.8 mmt
 - 3. Starting T_{ch} = 25°C, V_{DD} = 15 V, R_G = 25 Ω , V_{GS} = 20 \rightarrow 0 V, L = 100 μ H

PACKAGE DRAWING (Unit: mm)



EQUIVALENT CIRCUIT



Remark Strong electric field, when exposed to this device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred.

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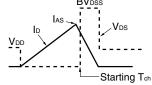


ELECTRICAL CHARACTERISTICS (TA = 25°C, All terminals are connected.)

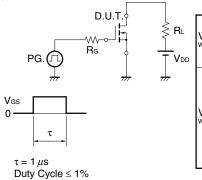
CHARACTERISTICS	SYMBOL	TEST CONDITIONS		TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	IDSS	V _{DS} = 30 V, V _{GS} = 0 V			10	μA
Gate Leakage Current	Igss	V _{GS} = ±16 V, V _{DS} = 0 V			±100	nA
Gate to Source Cut-off Voltage	V _{GS(off)}	V _{DS} = 10 V, I _D = 1 mA	1.5		2.5	V
Forward Transfer Admittance Note	y fs	V _{DS} = 10 V, I _D = 33 A	30			S
Drain to Source On-state Resistance Note	RDS(on)1	V _{GS} = 10 V, I _D = 65 A		1.6	2.0	mΩ
	R _{DS(on)2}	V _{GS} = 4.5 V, I _D = 33 A		2.3	2.9	mΩ
Input Capacitance	Ciss	V _{DS} = 15 V,		5370	6980	pF
Output Capacitance	Coss	V _{GS} = 0 V,		910	1180	pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		410	620	pF
Turn-on Delay Time	t _{d(on)}	V _{DD} = 15 V, I _D = 33 A,		33		ns
Rise Time	tr	V _{GS} = 10 V,		18		ns
Turn-off Delay Time	t _{d(off)}	R _G = 10 Ω		115		ns
Fall Time	tf			25		ns
Total Cata Charry	0	V _{GS} = 10 V		84	128	nC
Total Gate Charge	Q _G	V _{GS} = 5 V		43	66	nC
Gate to Source Charge	QGS	V _{DD} = 15 V		19		nC
Gate to Drain Charge	Q _{GD}	I _D = 65 A		13		nC
Body Diode Forward Voltage Note	V _{F(S-D)}	I _F = 65 A, V _{GS} = 0 V		0.83		V
Reverse Recovery Time	trr	IF = 65 A, VGS = 0 V,		45		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/μs		46		nC
Gate Resistance	Rg	f = 1 MHz		1.3	2.1	Ω

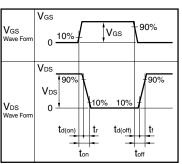
Note Pulsed

TEST CIRCUIT 1 AVALANCHE CAPABILITY



TEST CIRCUIT 2 SWITCHING TIME





TEST CIRCUIT 3 GATE CHARGE

$$\begin{array}{c|c} D.U.T. \\ \hline I_G = 2 \text{ mA} \\ \hline \end{array}$$

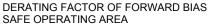
$$\begin{array}{c|c} PG. \\ \hline \end{array} \begin{array}{c} S \\ S \\ \end{array} \begin{array}{c} D.U.T. \\ \hline \end{array}$$

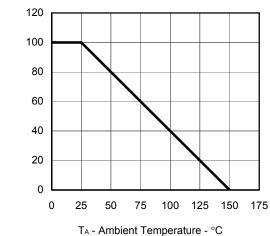


- Percentage of Rated Power - %

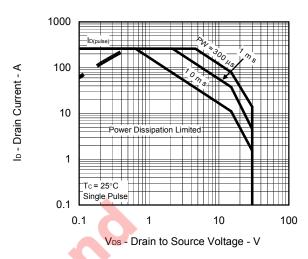
b - Drain Current - A

TYPICAL CHARACTERISTICS (TA = 25°C)

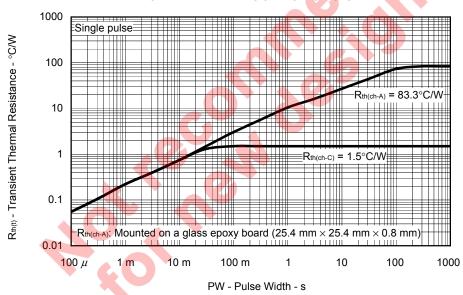




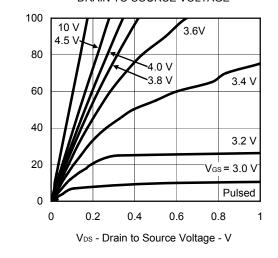
FORWARD BIAS SAFE OPERATING AREA



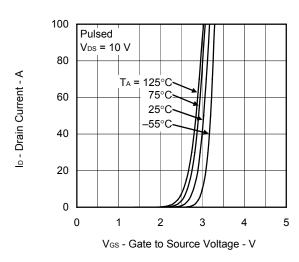
TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



DRAIN CURRENT vs.
DRAIN TO SOURCE VOLTAGE



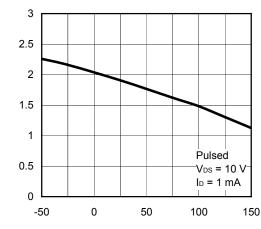
FORWARD TRANSFER CHARACTERISTICS



VGS(off) - Gate to Source Cut-off Voltage - V

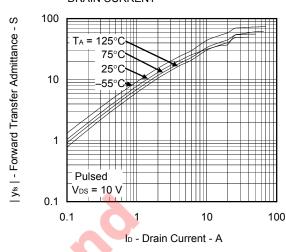
R_{DS(m)} - Drain to Source On-state Resistance - mΩ

GATE TO SOURCE CUT-OFF VOLTAGE vs. CHANNEL TEMPERATURE

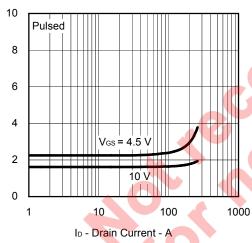


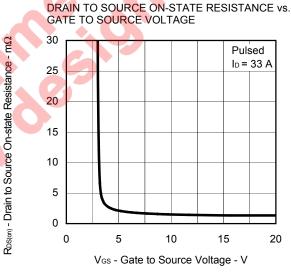
Tch - Channel Temperature - °C

FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT

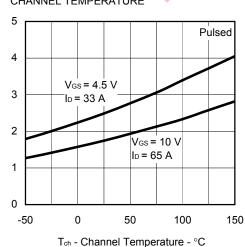


DRAIN TO SOURCE ON-STATE RESISTANCE vs. **DRAIN CURRENT**

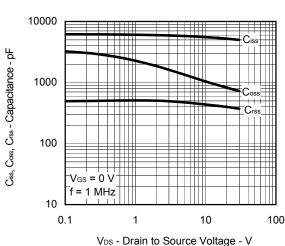




DRAIN TO SOURCE ON-STATE RESISTANCE vs. **CHANNEL TEMPERATURE**



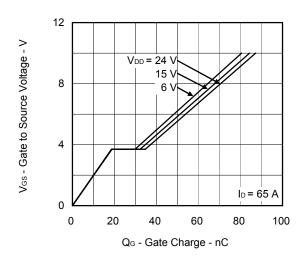
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



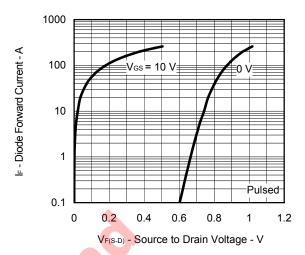
RDS(01) - Drain to Source On-state Resistance - m\Omega



DYNAMIC INPUT CHARACTERISTICS



SOURCE TO DRAIN DIODE FORWARD VOLTAGE



ORDERING INFORMATION

PART NUMBER	LEAD PLATING	PACKING	PACKAGE
μPA2744UT1A-E1-AY Note	Dura Ca	Ton 2 2000 n /22 al	8-pin HVSON (6051)
μPA2744UT1A-E2-AY Note	Pure Sn	Tape 3000 p/reel	0.10 g TYP.

Note Pb-free (This product does not contain Pb in the external electrode.)

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